



## SSC8036GS1

### N-Channel Enhancement Mode MOSFET

#### ➤ Features

VDS	VGS	RDSON Typ.	ID
30V	±20V	20mR@10V	6A
		30mR@4V5	

#### ➤ Description

This device uses advanced trench technology to provide excellent RDSON and low gate charge. This device is suitable for use as a load switch or in PWM applications.

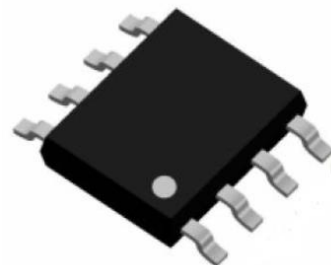
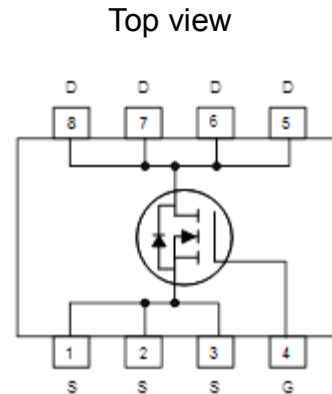
#### ➤ Applications

- Load Switch
- TFT panel power switch
- DCDC conversion

#### ➤ Ordering Information

Device	Package	Shipping
SSC8036GS1	SOP8	2500/Reel

#### ➤ Pin configuration



SOP8



Marking



➤ **Absolute Maximum Ratings**( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

Symbol	Parameter	Ratings	Unit
$V_{DSS}$	Drain-to-Source Voltage	30	V
$V_{GSS}$	Gate-to-Source Voltage	$\pm 20$	V
$I_D$	Continuous Drain Current <sup>a</sup>	6	A
$I_{DM}$	Pulsed Drain Current <sup>b</sup>	30	A
$P_D$	Power Dissipation <sup>c</sup>	4	W
$P_{DSM}$	Power Dissipation <sup>a</sup>	2	W
$T_J$	Operation junction temperature	-55 to 150	$^{\circ}\text{C}$
$T_{STG}$	Storage temperature range	-55 to 150	$^{\circ}\text{C}$

➤ **Thermal Resistance Ratings**( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

Symbol	Parameter	Typical	Maximum	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance <sup>a</sup>		70	$^{\circ}\text{C}/\text{W}$
$R_{\theta JC}$	Junction-to-Case Thermal Resistance		35	

Note:

- The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz.copper, in a still air environment with  $T_A=25^{\circ}\text{C}$ . The value in any given application depends on the user is specific board design. The current rating is based on the  $t \leq 10\text{s}$  thermal resistance rating.
- Repetitive rating, pulse width limited by junction temperature.
- The power dissipation  $P_D$  is based on  $T_{J(MAX)}=150^{\circ}\text{C}$ , using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

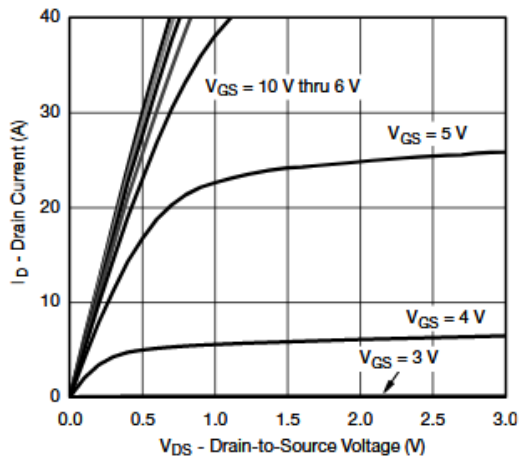


➤ **Electronics Characteristics**( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

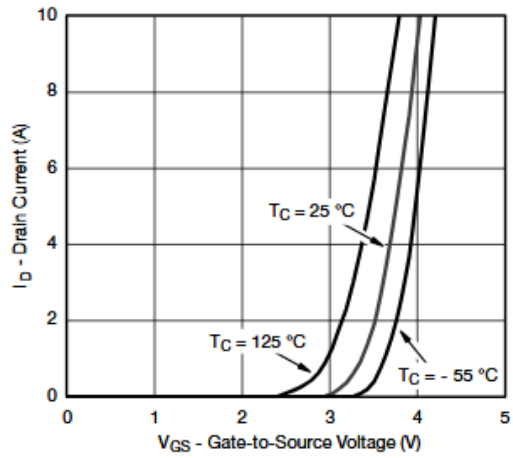
Symbol	Parameter	Test Conditions	Min	Typ.	Max	Unit
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	30			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.5	3	V
$R_{DS(on)}$	Drain-Source On- Resistance	$V_{GS}=10V, I_D=5.5A$		20	28	mR
		$V_{GS}=4.5V, I_D=4.5A$		30	43	
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS}=30V, V_{GS}=0V$			1	$\mu A$
$I_{GSS}$	Gate-Source leak current	$V_{GS}=\pm 20V, V_{DS}=0V$			$\pm 100$	nA
$G_{FS}$	Transconductance	$V_{DS}=5V, I_D=5A$		12		S
$V_{SD}$	Forward Voltage	$V_{GS}=0V, I_S=1A$			1.3	V
$C_{iss}$	Input Capacitance	$V_{DS}=15V, V_{GS}=0V, f=1MHz$		490		pF
$C_{oss}$	Output Capacitance			86		
$C_{rss}$	Reverse Transfer Capacitance			59		
$T_{D(ON)}$	Turn-on delay time	$V_{GEN}=10V,$ $V_{DS}=15V, R_L=15R,$ $R_G=3R, I_D=1A$		18		ns
$T_r$	Rise Time			32		
$T_{D(OFF)}$	Turn-off delay time			16		
$T_f$	Fall Time			33		
$Q_g$	Total Gate charge	$V_{GS}=10V, V_{DS}=10V, I_D=4A$		10.6		nC
$Q_{gs}$	Gate to Source charge			1.9		
$Q_{gd}$	Gate to Drain charge			2.1		



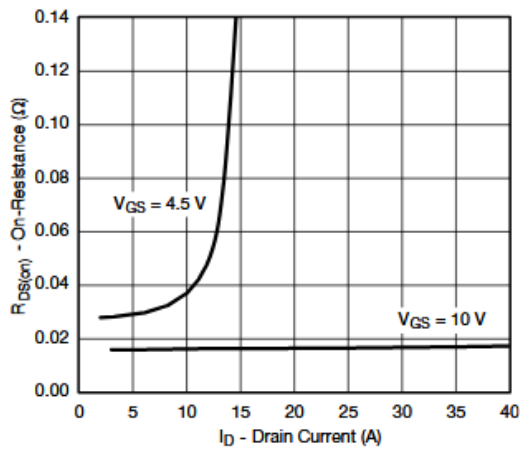
➤ **Typical Characteristics** ( $T_A=25^\circ\text{C}$  unless otherwise noted)



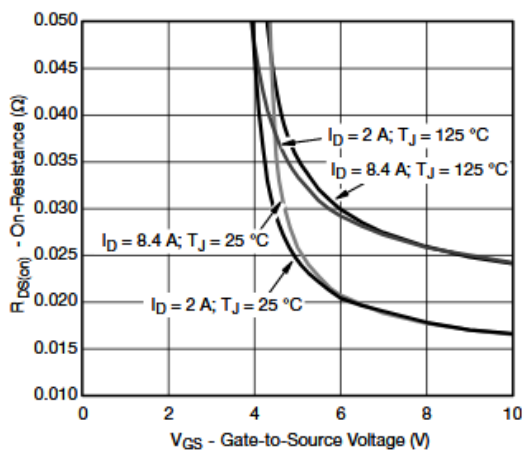
**Output Characteristics**



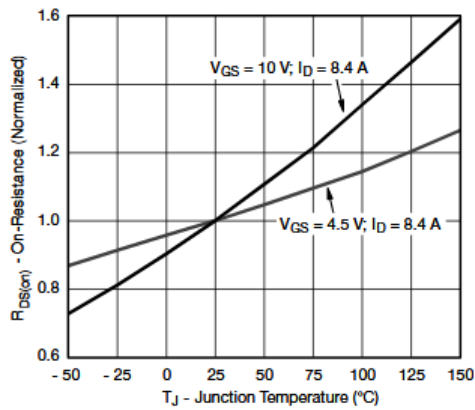
**Transfer Characteristics**



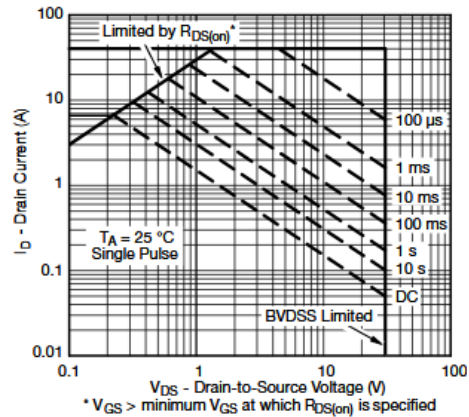
**On-Resistance vs. Drain Current**



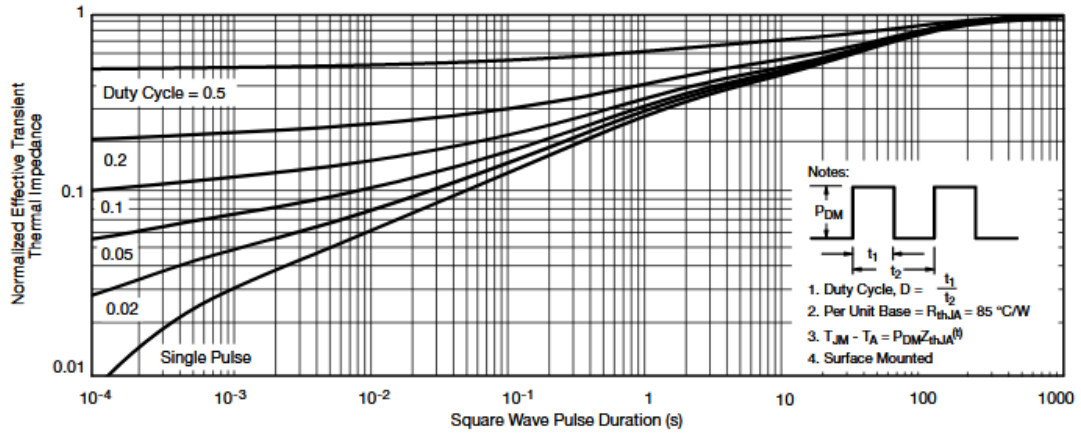
**On-Resistance vs. Gate-to-Source Voltage**



**On-Resistance vs. Junction Temperature**



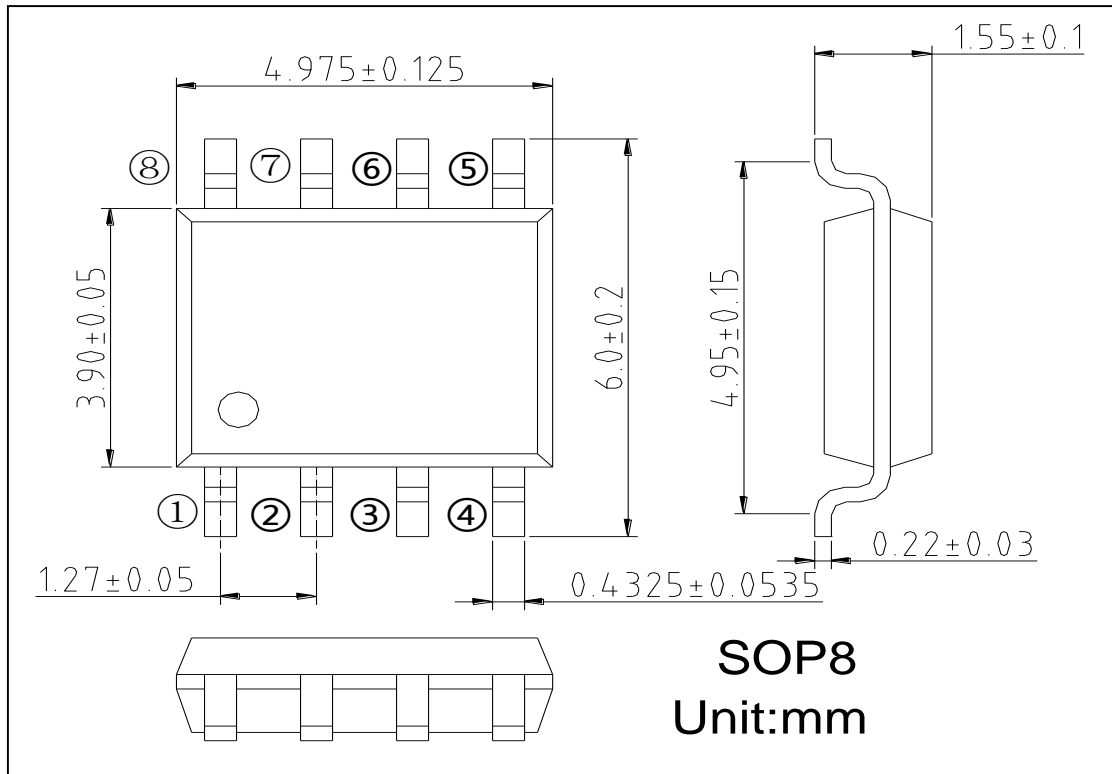
**Safe Operating Area, Junction-to-Ambient**



Normalized Thermal Transient Impedance, Junction-to-Ambient



➤ Package Information



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